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# 2SD1367

Silicon NPN Epitaxial

# HITACHI

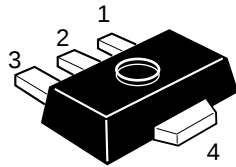
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## Application

- Low frequency power amplifier
- Complementary pair with 2SB1001

## Outline

UPAK



1. Base
2. Collector
3. Emitter
4. Collector (Flange)

Absolute Maximum Ratings (Ta = 25°C)

| Item                         | Symbol             | Ratings     | Unit |
|------------------------------|--------------------|-------------|------|
| Collector to base voltage    | $V_{CBO}$          | 20          | V    |
| Collector to emitter voltage | $V_{CEO}$          | 16          | V    |
| Emitter to base voltage      | $V_{EBO}$          | 6           | V    |
| Collector current            | $I_C$              | 2           | A    |
| Collector peak current       | $i_{C(peak)}^{*1}$ | 3           | A    |
| Collector power dissipation  | $P_C^{*2}$         | 1           | W    |
| Junction temperature         | $T_j$              | 150         | °C   |
| Storage temperature          | $T_{stg}$          | −55 to +150 | °C   |

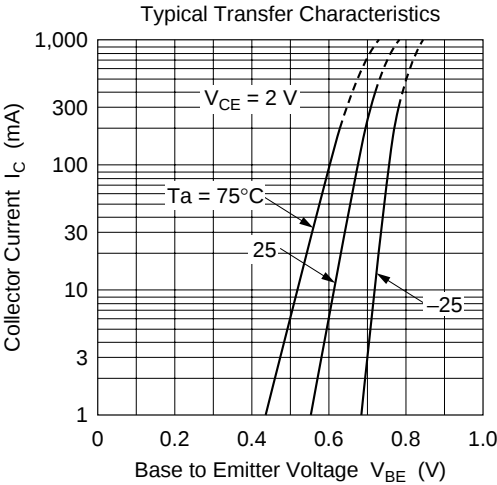
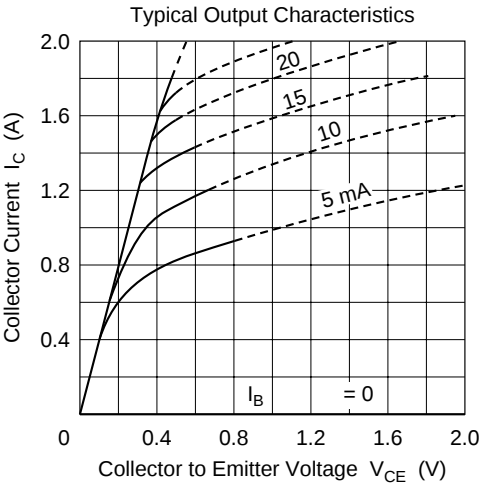
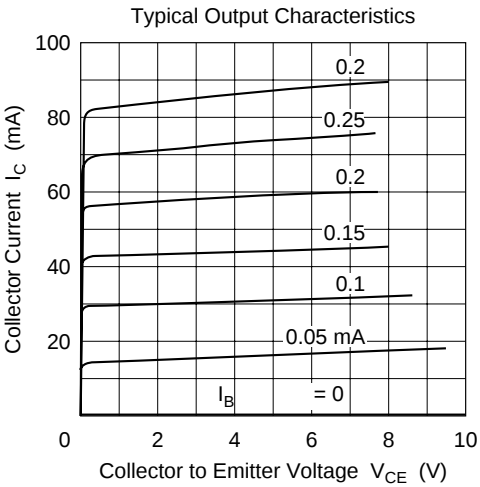
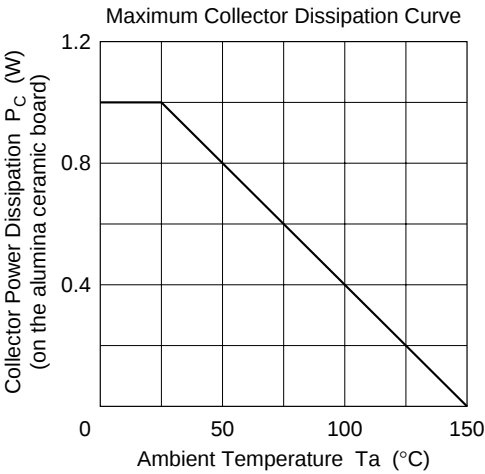
Notes: 1.  $PW \leq 10$  ms, Duty cycle  $\leq 20\%$ .  
2. Value on the alumina ceramic board (12.5 × 20 × 0.7 mm)

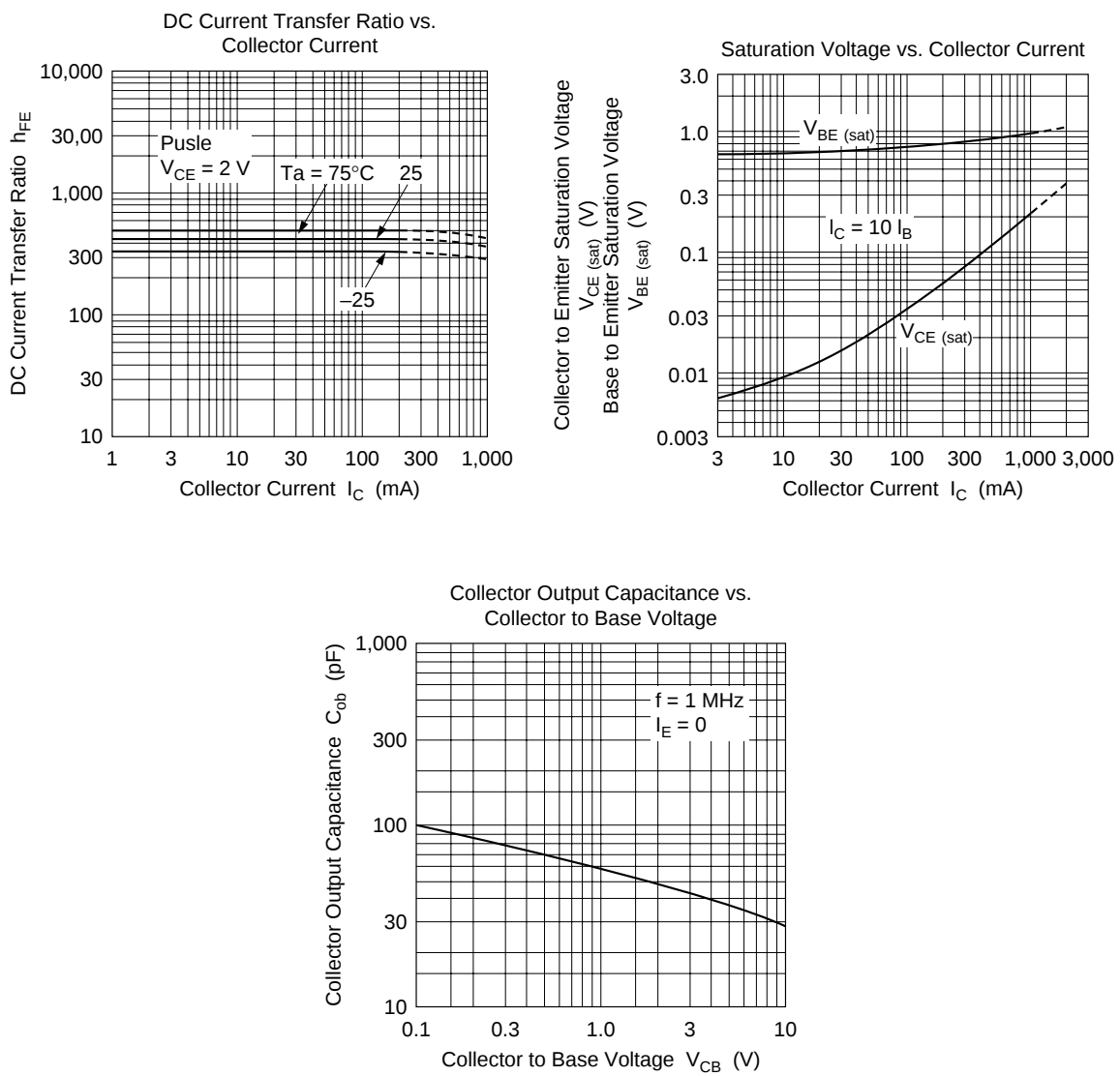
Electrical Characteristics (Ta = 25°C)

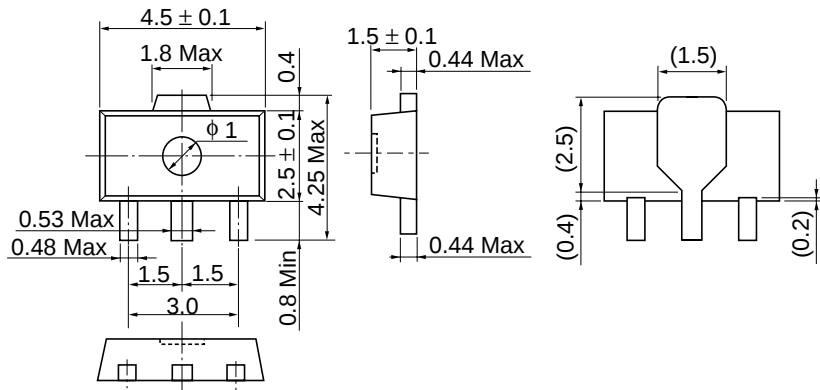
| Item                                    | Symbol        | Min | Typ  | Max | Unit          | Test conditions                                         |
|-----------------------------------------|---------------|-----|------|-----|---------------|---------------------------------------------------------|
| Collector to base breakdown voltage     | $V_{(BR)CBO}$ | 20  | —    | —   | V             | $I_C = 10\text{ }\mu\text{A}$ , $I_E = 0$               |
| Collector to emitter breakdown voltage  | $V_{(BR)CEO}$ | 16  | —    | —   | V             | $I_C = 1\text{ mA}$ , $R_{BE} = \infty$                 |
| Emitter to base breakdown voltage       | $V_{(BR)EBO}$ | 6   | —    | —   | V             | $I_E = 10\text{ }\mu\text{A}$ , $I_C = 0$               |
| Collector cutoff current                | $I_{CBO}$     | —   | —    | 0.1 | $\mu\text{A}$ | $V_{CB} = 16\text{ V}$ , $I_E = 0$                      |
| Emitter cutoff current                  | $I_{EBO}$     | —   | —    | 0.1 | $\mu\text{A}$ | $V_{EB} = 5\text{ V}$ , $I_C = 0$                       |
| DC current transfer ratio               | $h_{FE}^{*1}$ | 100 | —    | 500 |               | $V_{CE} = 2\text{ V}$ , $I_C = 0.1\text{ A}$ , Pulse    |
| Collector to emitter saturation voltage | $V_{CE(sat)}$ | —   | 0.15 | 0.3 | V             | $I_C = 1\text{ A}$ , $I_B = 0.1\text{ A}$ , Pulse       |
| Base to emitter saturation voltage      | $V_{BE(sat)}$ | —   | 0.9  | 1.2 | V             | $I_C = 1\text{ A}$ , $I_B = 0.1\text{ A}$ , Pulse       |
| Gain bandwidth product                  | $f_T$         | —   | 100  | —   | MHz           | $V_{CE} = 2\text{ V}$ , $I_C = 10\text{ mA}$            |
| Collector output capacitance            | $C_{ob}$      | —   | 20   | —   | pF            | $V_{CB} = 10\text{ V}$ , $I_E = 0$ , $f = 1\text{ MHz}$ |

Note: 1. The 2SD1367 is grouped by  $h_{FE}$  as follows.

| Mark     | BA         | BB         | BC         |
|----------|------------|------------|------------|
| $h_{FE}$ | 100 to 200 | 160 to 320 | 250 to 500 |







|                          |          |
|--------------------------|----------|
| Hitachi Code             | UPAK     |
| JEDEC                    | —        |
| EIAJ                     | Conforms |
| Weight (reference value) | 0.050 g  |

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